



**THE DATASHEET OF
BZB84-C8V2,215**



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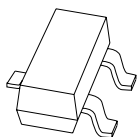
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Kind regards,

Team Nexperia



BZB84 series

Dual Zener diodes

Rev. 03 — 9 June 2009

Product data sheet

1. Product profile

1.1 General description

General-purpose Zener diodes in a SOT23 (TO-236AB) small Surface-Mounted Device (SMD) plastic package.

1.2 Features

- Non-repetitive peak reverse power dissipation: ≤ 40 W
- Total power dissipation: ≤ 300 mW
- Two tolerance series:
B = ± 2 % and C = ± 5 %
- Wide working voltage range:
nominal 2.4 V to 75 V (E24 range)
- Small plastic package suitable for surface-mounted design
- Dual common anode configuration
- AEC-Q101 qualified

1.3 Applications

- General regulation functions

1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------|---|---------------|-------|-----|-----|------|
| Per diode | | | | | | |
| V_F | forward voltage | $I_F = 10$ mA | [1] - | - | 0.9 | V |
| P_{ZSM} | non-repetitive peak reverse power dissipation | | [2] - | - | 40 | W |

[1] Pulse test: $t_p \leq 300$ μ s; $\delta \leq 0.02$.

[2] $t_p = 100$ μ s; square wave; $T_j = 25$ °C prior to surge

2. Pinning information

Table 2. Pinning

| Pin | Description | Simplified outline | Graphic symbol |
|-----|-------------------|---|---|
| 1 | cathode (diode 1) |  |  |
| 2 | cathode (diode 2) | | |
| 3 | common anode | | |

006aaa154

3. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|--|---------|--|---------|
| | Name | Description | Version |
| BZB84-B2V4 to BZB84-C75 ^[1] | - | plastic surface-mounted package; 3 leads | SOT23 |

[1] The series consists of 74 types with nominal working voltages from 2.4 V to 75 V.

4. Marking

Table 4. Marking codes

| Type number | Marking code ^[1] | Type number | Marking code ^[1] |
|-------------|-----------------------------|-------------|-----------------------------|
| BZB84-B2V4 | V9* | BZB84-C2V4 | U9* |
| BZB84-B2V7 | VA* | BZB84-C2V7 | UA* |
| BZB84-B3V0 | VB* | BZB84-C3V0 | UB* |
| BZB84-B3V3 | VC* | BZB84-C3V3 | UC* |
| BZB84-B3V6 | VD* | BZB84-C3V6 | UD* |
| BZB84-B3V9 | VE* | BZB84-C3V9 | UE* |
| BZB84-B4V3 | VF* | BZB84-C4V3 | UF* |
| BZB84-B4V7 | VG* | BZB84-C4V7 | UG* |
| BZB84-B5V1 | VH* | BZB84-C5V1 | UH* |
| BZB84-B5V6 | VK* | BZB84-C5V6 | UK* |
| BZB84-B6V2 | VL* | BZB84-C6V2 | UL* |
| BZB84-B6V8 | VM* | BZB84-C6V8 | UM* |
| BZB84-B7V5 | VN* | BZB84-C7V5 | UN* |
| BZB84-B8V2 | VP* | BZB84-C8V2 | UP* |
| BZB84-B9V1 | VR* | BZB84-C9V1 | UR* |

Table 4. Marking codes ...continued

| Type number | Marking code ^[1] | Type number | Marking code ^[1] |
|-------------|-----------------------------|-------------|-----------------------------|
| BZB84-B10 | VS* | BZB84-C10 | US* |
| BZB84-B11 | VT* | BZB84-C11 | UT* |
| BZB84-B12 | VU* | BZB84-C12 | UU* |
| BZB84-B13 | VV* | BZB84-C13 | UV* |
| BZB84-B15 | VW* | BZB84-C15 | UW* |
| BZB84-B16 | PT* | BZB84-C16 | PB* |
| BZB84-B18 | PU* | BZB84-C18 | PC* |
| BZB84-B20 | RP* | BZB84-C20 | RQ* |
| BZB84-B22 | PV* | BZB84-C22 | PD* |
| BZB84-B24 | PW* | BZB84-C24 | PE* |
| BZB84-B27 | PX* | BZB84-C27 | PF* |
| BZB84-B30 | PY* | BZB84-C30 | PG* |
| BZB84-B33 | PZ* | BZB84-C33 | PH* |
| BZB84-B36 | RA* | BZB84-C36 | PJ* |
| BZB84-B39 | RB* | BZB84-C39 | PK* |
| BZB84-B43 | RC* | BZB84-C43 | PL* |
| BZB84-B47 | RD* | BZB84-C47 | PM* |
| BZB84-B51 | RE* | BZB84-C51 | PN* |
| BZB84-B56 | RF* | BZB84-C56 | PP* |
| BZB84-B62 | RG* | BZB84-C62 | PQ* |
| BZB84-B68 | RH* | BZB84-C68 | PR* |
| BZB84-B75 | RJ* | BZB84-C75 | PS* |

[1] * = -: made in Hong Kong
 * = p: made in Hong Kong
 * = t: made in Malaysia
 * = W: made in China

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---|------------|-------|---|------|
| Per diode | | | | | |
| I_F | forward current | | - | 200 | mA |
| I_{ZSM} | non-repetitive peak reverse current | | [1] - | see Table 8 , 9 , 10 and 11 | |
| P_{ZSM} | non-repetitive peak reverse power dissipation | | [1] - | 40 | W |

Table 5. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-------------------|-------------------------|------------------------------------|-------|------|------|
| Per device | | | | | |
| P_{tot} | total power dissipation | $T_{\text{amb}} \leq 25\text{ °C}$ | [2] - | 300 | mW |
| T_j | junction temperature | | - | 150 | °C |
| T_{amb} | ambient temperature | | -55 | +150 | °C |
| T_{stg} | storage temperature | | -65 | +150 | °C |

[1] $t_p = 100\text{ }\mu\text{s}$; square wave; $T_j = 25\text{ °C}$ prior to surge

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|--|-------------|-------|-----|-----|------|
| Per device; single diode loaded | | | | | | |
| $R_{\text{th}(j-a)}$ | thermal resistance from junction to ambient | in free air | [1] - | - | 417 | K/W |
| $R_{\text{th}(j-sp)}$ | thermal resistance from junction to solder point | | [2] - | - | 100 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Soldering points at pins 1 and 2.

7. Characteristics

Table 7. Characteristics $T_j = 25\text{ °C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------|-----------------|----------------------|-------|-----|-----|------|
| Per diode | | | | | | |
| V_F | forward voltage | $I_F = 10\text{ mA}$ | [1] - | - | 0.9 | V |

[1] Pulse test: $t_p \leq 300\text{ }\mu\text{s}$; $\delta \leq 0.02$.

Table 8. Characteristics per type; BZB84-B2V4 to BZB84-B24 $T_j = 25\text{ °C}$ unless otherwise specified.

| BZB84-Bxxx | Working voltage V_Z (V) | | Differential resistance r_{dif} (Ω) | | Reverse current I_R (μA) | | Temperature coefficient S_Z (mV/K) | | Diode capacitance C_d (pF) ^[1] | Non-repetitive peak reverse current I_{ZSM} (A) ^[2] |
|------------|------------------------------|-------|--|---------------------|--|-----------|---|------|--|---|
| | $I_Z = 5\text{ mA}$ | | $I_Z = 1\text{ mA}$ | $I_Z = 5\text{ mA}$ | Max | V_R (V) | $I_Z = 5\text{ mA}$ | | | |
| | Min | Max | Max | Max | | | Min | Max | Max | Max |
| 2V4 | 2.35 | 2.45 | 600 | 100 | 50 | 1 | -3.5 | 0 | 450 | 6.0 |
| 2V7 | 2.65 | 2.75 | 600 | 100 | 20 | 1 | -3.5 | 0 | 450 | 6.0 |
| 3V0 | 2.94 | 3.06 | 600 | 95 | 10 | 1 | -3.5 | 0 | 450 | 6.0 |
| 3V3 | 3.23 | 3.37 | 600 | 95 | 5 | 1 | -3.5 | 0 | 450 | 6.0 |
| 3V6 | 3.53 | 3.67 | 600 | 90 | 5 | 1 | -3.5 | 0 | 450 | 6.0 |
| 3V9 | 3.82 | 3.98 | 600 | 90 | 3 | 1 | -3.5 | 0 | 450 | 6.0 |
| 4V3 | 4.21 | 4.39 | 600 | 90 | 3 | 1 | -3.5 | 0 | 450 | 6.0 |
| 4V7 | 4.61 | 4.79 | 500 | 80 | 3 | 2 | -3.5 | 0.2 | 300 | 6.0 |
| 5V1 | 5.00 | 5.20 | 480 | 60 | 2 | 2 | -2.7 | 1.2 | 300 | 6.0 |
| 5V6 | 5.49 | 5.71 | 400 | 40 | 1 | 2 | -2.0 | 2.5 | 300 | 6.0 |
| 6V2 | 6.08 | 6.32 | 150 | 10 | 3 | 4 | 0.4 | 3.7 | 200 | 6.0 |
| 6V8 | 6.66 | 6.94 | 80 | 15 | 2 | 4 | 1.2 | 4.5 | 200 | 6.0 |
| 7V5 | 7.35 | 7.65 | 80 | 15 | 1 | 5 | 2.5 | 5.3 | 150 | 4.0 |
| 8V2 | 8.04 | 8.36 | 80 | 15 | 0.70 | 5 | 3.2 | 6.2 | 150 | 4.0 |
| 9V1 | 8.92 | 9.28 | 100 | 15 | 0.50 | 6 | 3.8 | 7.0 | 150 | 3.0 |
| 10 | 9.80 | 10.20 | 150 | 20 | 0.20 | 7 | 4.5 | 8.0 | 90 | 3.0 |
| 11 | 10.80 | 11.20 | 150 | 20 | 0.10 | 8 | 5.4 | 9.0 | 85 | 2.5 |
| 12 | 11.80 | 12.20 | 150 | 25 | 0.10 | 8 | 6.0 | 10.0 | 85 | 2.5 |
| 13 | 12.70 | 13.30 | 170 | 30 | 0.10 | 8 | 7.0 | 11.0 | 80 | 2.5 |
| 15 | 14.70 | 15.30 | 200 | 30 | 0.05 | 10.5 | 9.2 | 13.0 | 75 | 2.0 |
| 16 | 15.70 | 16.30 | 200 | 40 | 0.05 | 11.2 | 10.4 | 14.0 | 75 | 1.5 |
| 18 | 17.60 | 18.40 | 225 | 45 | 0.05 | 12.6 | 12.4 | 16.0 | 70 | 1.5 |
| 20 | 19.6 | 20.4 | 225 | 55 | 0.05 | 14.0 | 14.4 | 18.0 | 60 | 1.5 |
| 22 | 21.6 | 22.4 | 250 | 55 | 0.05 | 15.4 | 16.4 | 20.0 | 60 | 1.25 |
| 24 | 23.5 | 24.5 | 250 | 70 | 0.05 | 16.8 | 18.4 | 22.0 | 55 | 1.25 |

[1] $f = 1\text{ MHz}$; $V_R = 0\text{ V}$ [2] $t_p = 100\text{ }\mu\text{s}$; square wave; $T_j = 25\text{ °C}$ prior to surge

Table 9. Characteristics per type; BZB84-B27 to BZB84-B75

$T_j = 25\text{ °C}$ unless otherwise specified.

| BZB84-Bxxx | Working voltage V_Z (V) | | Differential resistance r_{dif} (Ω) | | Reverse current I_R (μ A) | | Temperature coefficient S_Z (mV/K) | | Diode capacitance C_d (pF) ^[1] | Non-repetitive peak reverse current I_{ZSM} (A) ^[2] |
|------------|---------------------------|------|--|---------------------|----------------------------------|-----------|--------------------------------------|------|---|--|
| | $I_Z = 2\text{ mA}$ | | $I_Z = 0.5\text{ mA}$ | $I_Z = 2\text{ mA}$ | Max | V_R (V) | $I_Z = 2\text{ mA}$ | | | |
| | Min | Max | Max | Max | | | Min | Max | Max | Max |
| 27 | 26.5 | 27.5 | 300 | 80 | 0.05 | 18.9 | 21.4 | 25.3 | 50 | 1.00 |
| 30 | 29.4 | 30.6 | 300 | 80 | 0.05 | 21.0 | 24.4 | 29.4 | 50 | 1.00 |
| 33 | 32.3 | 33.7 | 325 | 80 | 0.05 | 23.1 | 27.4 | 33.4 | 45 | 0.90 |
| 36 | 35.3 | 36.7 | 350 | 90 | 0.05 | 25.2 | 30.4 | 37.4 | 45 | 0.80 |
| 39 | 38.2 | 39.8 | 350 | 130 | 0.05 | 27.3 | 33.4 | 41.2 | 45 | 0.70 |
| 43 | 42.1 | 43.9 | 375 | 150 | 0.05 | 30.1 | 37.6 | 46.6 | 40 | 0.60 |
| 47 | 46.1 | 47.9 | 375 | 170 | 0.05 | 32.9 | 42.0 | 51.8 | 40 | 0.50 |
| 51 | 50.0 | 52.0 | 400 | 180 | 0.05 | 35.7 | 46.6 | 57.2 | 40 | 0.40 |
| 56 | 54.9 | 57.1 | 425 | 200 | 0.05 | 39.2 | 52.2 | 63.8 | 40 | 0.30 |
| 62 | 60.8 | 63.2 | 450 | 215 | 0.05 | 43.4 | 58.8 | 71.6 | 35 | 0.30 |
| 68 | 66.6 | 69.4 | 475 | 240 | 0.05 | 47.6 | 65.6 | 79.8 | 35 | 0.25 |
| 75 | 73.5 | 76.5 | 500 | 255 | 0.05 | 52.5 | 73.4 | 88.6 | 35 | 0.20 |

[1] $f = 1\text{ MHz}$; $V_R = 0\text{ V}$

[2] $t_p = 100\text{ }\mu\text{s}$; square wave; $T_j = 25\text{ °C}$ prior to surge

Table 10. Characteristics per type; BZB84-C2V4 to BZB84-C24

 $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified.

| BZB84-Cxxx | Working voltage V_Z (V) | | Differential resistance r_{dif} (Ω) | | Reverse current I_R (μA) | | Temperature coefficient S_Z (mV/K) | | Diode capacitance C_d (pF) ^[1] | Non-repetitive peak reverse current I_{ZSM} (A) ^[2] |
|------------|------------------------------|------|--|---------------------|--|-----------|---|------|--|---|
| | $I_Z = 5\text{ mA}$ | | $I_Z = 1\text{ mA}$ | $I_Z = 5\text{ mA}$ | Max | V_R (V) | $I_Z = 5\text{ mA}$ | | | |
| | Min | Max | Max | Max | | | Min | Max | Max | Max |
| 2V4 | 2.2 | 2.6 | 600 | 100 | 50 | 1 | -3.5 | 0 | 450 | 6.0 |
| 2V7 | 2.5 | 2.9 | 600 | 100 | 20 | 1 | -3.5 | 0 | 450 | 6.0 |
| 3V0 | 2.8 | 3.2 | 600 | 95 | 10 | 1 | -3.5 | 0 | 450 | 6.0 |
| 3V3 | 3.1 | 3.5 | 600 | 95 | 5 | 1 | -3.5 | 0 | 450 | 6.0 |
| 3V6 | 3.4 | 3.8 | 600 | 90 | 5 | 1 | -3.5 | 0 | 450 | 6.0 |
| 3V9 | 3.7 | 4.1 | 600 | 90 | 3 | 1 | -3.5 | 0 | 450 | 6.0 |
| 4V3 | 4.0 | 4.6 | 600 | 90 | 3 | 1 | -3.5 | 0 | 450 | 6.0 |
| 4V7 | 4.4 | 5.0 | 500 | 80 | 3 | 2 | -3.5 | 0.2 | 300 | 6.0 |
| 5V1 | 4.8 | 5.4 | 480 | 60 | 2 | 2 | -2.7 | 1.2 | 300 | 6.0 |
| 5V6 | 5.2 | 6.0 | 400 | 40 | 1 | 2 | -2.0 | 2.5 | 300 | 6.0 |
| 6V2 | 5.8 | 6.6 | 150 | 10 | 3 | 4 | 0.4 | 3.7 | 200 | 6.0 |
| 6V8 | 6.4 | 7.2 | 80 | 15 | 2 | 4 | 1.2 | 4.5 | 200 | 6.0 |
| 7V5 | 7.0 | 7.9 | 80 | 15 | 1 | 5 | 2.5 | 5.3 | 150 | 4.0 |
| 8V2 | 7.7 | 8.7 | 80 | 15 | 0.70 | 5 | 3.2 | 6.2 | 150 | 4.0 |
| 9V1 | 8.5 | 9.6 | 100 | 15 | 0.50 | 6 | 3.8 | 7.0 | 150 | 3.0 |
| 10 | 9.4 | 10.6 | 150 | 20 | 0.20 | 7 | 4.5 | 8.0 | 90 | 3.0 |
| 11 | 10.4 | 11.6 | 150 | 20 | 0.10 | 8 | 5.4 | 9.0 | 85 | 2.5 |
| 12 | 11.4 | 12.7 | 150 | 25 | 0.10 | 8 | 6.0 | 10.0 | 85 | 2.5 |
| 13 | 12.4 | 14.1 | 170 | 30 | 0.10 | 8 | 7.0 | 11.0 | 80 | 2.5 |
| 15 | 13.8 | 15.6 | 200 | 30 | 0.05 | 10.5 | 9.2 | 13.0 | 75 | 2.0 |
| 16 | 15.3 | 17.1 | 200 | 40 | 0.05 | 11.2 | 10.4 | 14.0 | 75 | 1.5 |
| 18 | 16.8 | 19.1 | 225 | 45 | 0.05 | 12.6 | 12.4 | 16.0 | 70 | 1.5 |
| 20 | 18.8 | 21.2 | 225 | 55 | 0.05 | 14.0 | 14.4 | 18.0 | 60 | 1.5 |
| 22 | 20.8 | 23.3 | 250 | 55 | 0.05 | 15.4 | 16.4 | 20.0 | 60 | 1.25 |
| 24 | 22.8 | 25.6 | 250 | 70 | 0.05 | 16.8 | 18.4 | 22.0 | 55 | 1.25 |

[1] $f = 1\text{ MHz}$; $V_R = 0\text{ V}$ [2] $t_p = 100\text{ }\mu\text{s}$; square wave; $T_j = 25\text{ }^\circ\text{C}$ prior to surge

Table 11. Characteristics per type; BZB84-C27 to BZB84-C75

$T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified.

| BZB84-Cxxx | Working voltage V_Z (V) | | Differential resistance r_{dif} (Ω) | | Reverse current I_R (μA) | | Temperature coefficient S_Z (mV/K) | | Diode capacitance C_d (pF) ^[1] | Non-repetitive peak reverse current I_{ZSM} (A) ^[2] |
|------------|---------------------------|------|--|---------------------|---|---------------------|--------------------------------------|------|---|--|
| | $I_Z = 2\text{ mA}$ | | $I_Z = 0.5\text{ mA}$ | $I_Z = 2\text{ mA}$ | V_R (V) | $I_Z = 2\text{ mA}$ | | | | |
| | Min | Max | Max | Max | | Max | Min | Max | Max | Max |
| 27 | 25.1 | 28.9 | 300 | 80 | 0.05 | 18.9 | 21.4 | 25.3 | 50 | 1.00 |
| 30 | 28.0 | 32.0 | 300 | 80 | 0.05 | 21.0 | 24.4 | 29.4 | 50 | 1.00 |
| 33 | 31.0 | 35.0 | 325 | 80 | 0.05 | 23.1 | 27.4 | 33.4 | 45 | 0.90 |
| 36 | 34.0 | 38.0 | 350 | 90 | 0.05 | 25.2 | 30.4 | 37.4 | 45 | 0.80 |
| 39 | 37.0 | 41.0 | 350 | 130 | 0.05 | 27.3 | 33.4 | 41.2 | 45 | 0.70 |
| 43 | 40.0 | 46.0 | 375 | 150 | 0.05 | 30.1 | 37.6 | 46.6 | 40 | 0.60 |
| 47 | 44.0 | 50.0 | 375 | 170 | 0.05 | 32.9 | 42.0 | 51.8 | 40 | 0.50 |
| 51 | 48.0 | 54.0 | 400 | 180 | 0.05 | 35.7 | 46.6 | 57.2 | 40 | 0.40 |
| 56 | 52.0 | 60.0 | 425 | 200 | 0.05 | 39.2 | 52.2 | 63.8 | 40 | 0.30 |
| 62 | 58.0 | 66.0 | 450 | 215 | 0.05 | 43.4 | 58.8 | 71.6 | 35 | 0.30 |
| 68 | 64.0 | 72.0 | 475 | 240 | 0.05 | 47.6 | 65.6 | 79.8 | 35 | 0.25 |
| 75 | 70.0 | 79.0 | 500 | 255 | 0.05 | 52.5 | 73.4 | 88.6 | 35 | 0.20 |

[1] $f = 1\text{ MHz}$; $V_R = 0\text{ V}$

[2] $t_p = 100\text{ }\mu\text{s}$; square wave; $T_j = 25\text{ }^\circ\text{C}$ prior to surge





$T_j = 25\text{ }^\circ\text{C to }150\text{ }^\circ\text{C}$
BZB84-B/C2V4 to BZB84-B/C4V3

Fig 3. Per diode: Temperature coefficient as a function of working current; typical values



$T_j = 25\text{ }^\circ\text{C to }150\text{ }^\circ\text{C}$
BZB84-B/C4V7 to BZB84-B/C12

Fig 4. Per diode: Temperature coefficient as a function of working current; typical values



$T_j = 25\text{ }^\circ\text{C}$
BZB84-B/C2V7 to BZB84-B/C8V2

Fig 5. Per diode: Working current as a function of working voltage; typical values



$T_j = 25\text{ }^\circ\text{C}$
BZB84-B/C10 to BZB84-B/C36

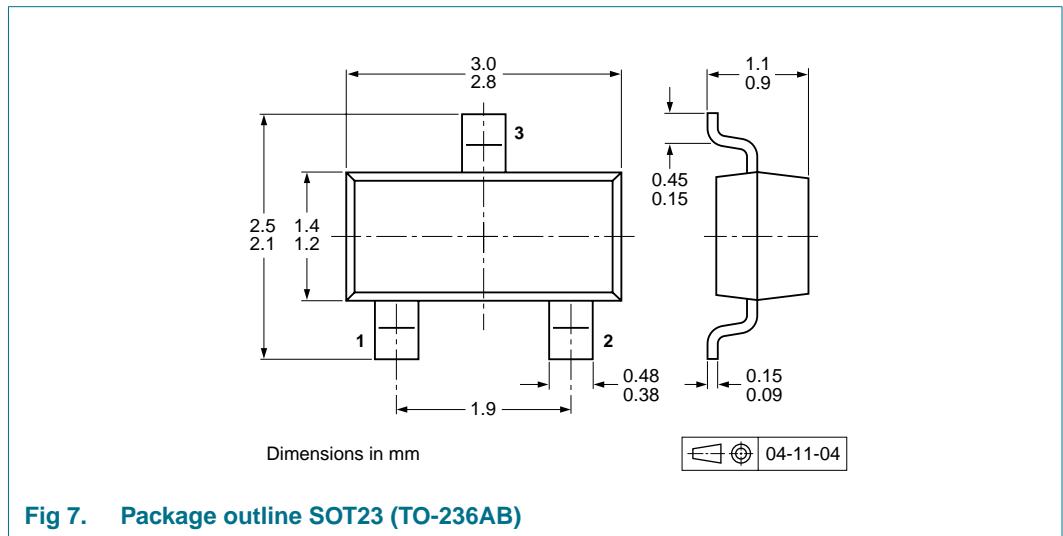
Fig 6. Per diode: Working current as a function of working voltage; typical values

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

Table 12. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.^[1]

| Type number | Package | Description | Packing quantity | |
|--|---------|--------------------------------|------------------|-------|
| | | | 3000 | 10000 |
| BZB84-B2V4 to BZB84-C75 ^[2] | SOT23 | 4 mm pitch, 8 mm tape and reel | -215 | -235 |

[1] For further information and the availability of packing methods, see [Section 14](#).

[2] The series consists of 74 types with nominal working voltages from 2.4 V to 75 V.

11. Soldering

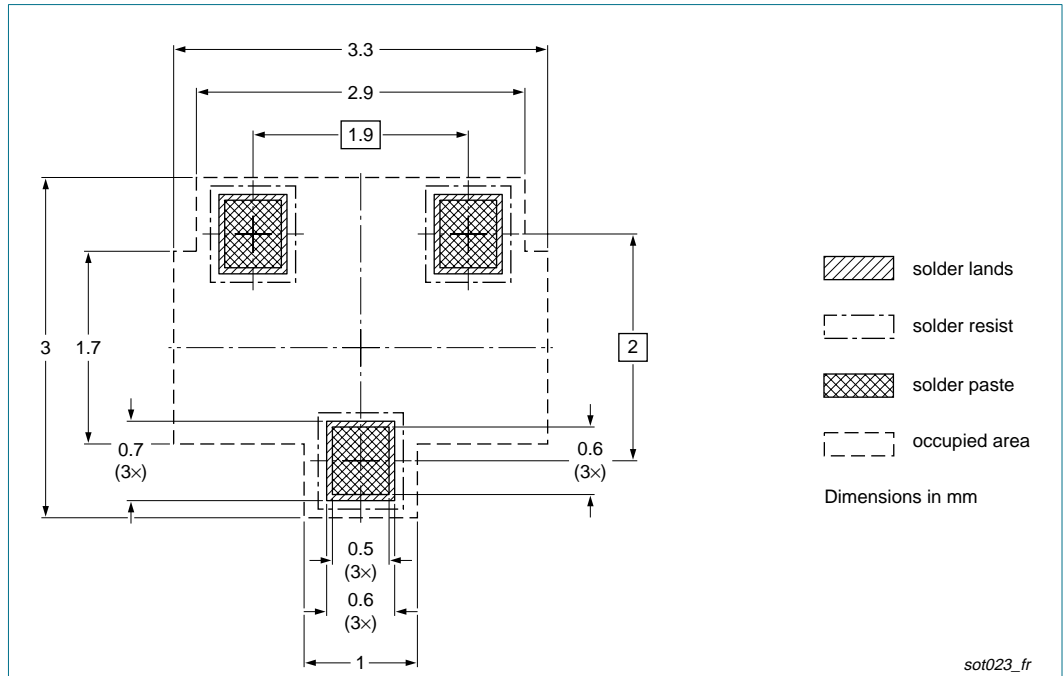


Fig 8. Reflow soldering footprint SOT23 (TO-236AB)



Fig 9. Wave soldering footprint SOT23 (TO-236AB)

12. Revision history

Table 13. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--------------|---|---------------|-------------|
| BZB84_SER_3 | 20090609 | Product data sheet | - | BZB84_SER_2 |
| Modifications: | | <ul style="list-style-type: none">• Table 5 “Limiting values”: P_{tot} maximum value amended• Table 6: R_{th} maximum values amended• Section 13 “Legal information”: updated | | |
| BZB84_SER_2 | 20090223 | Product data sheet | - | BZB84_SER_1 |
| BZB84_SER_1 | 20080514 | Product data sheet | - | - |

13. Legal information

13.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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